ID de Contribution: **24** Type: **Non spécifié**

Vittorio Romano: "Analytical and simulation aspects of charge transport in graphene"

vendredi 20 janvier 2023 11:30 (55 minutes)

The last years have witnessed a great interest for 2D-materials due to their promising applications. One of the most investigated is graphene which is considered as a potential new material to be exploited in nano-electronic and optoelectronic devices.
Charge transport in graphene can be described with several degrees of physical complexity [1]. At quantum level an accurate model is represented by the Wigner equation but in several cases its semiclassical limit, the Boltzmann equation, constitutes a fully acceptable model. However, the numerical difficulties encountered in the direct solution of both the Wigner and the semiclassical Boltzmann equation has prompted the development of hydrodynamical, energy transport and drift diffusion models, in view of the design of a future generation of electron devices where graphene replaces standard semiconductors like silicon and gallium arsenide. Moreover, thermal effects in low dimensional structures play a relevant role and, therefore, phonon transport must be also included.
Interesting new mathematical issues related to the peculiar features of graphene arise. The main aspects will be discussed and recent results [2-13] illustrated in the perspective of future developments, in particular the design and optimization of graphene field effect transistors.

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